

CX2SM CRYSTAL

760 kHz to 1.35 MHz Low Profile Miniature Surface Mount Quartz Crystal

DESCRIPTION

The CX2SM quartz crystals are leadless devices designed for surface mounting on printed circuit boards or hybrid substrates. They are hermetically sealed in a rugged, miniature ceramic package. They are manufactured using the STATEK-developed photolithographic process, and were designed utilizing the experience acquired by producing millions of crystals for industrial, commercial, military and medical applications. Maximum process temperature should not exceed 260°C.

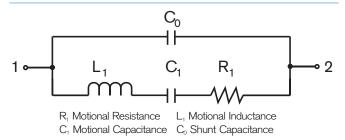


PACKAGE DIMENSIONS

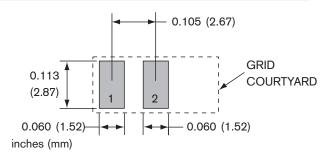
FEATURES

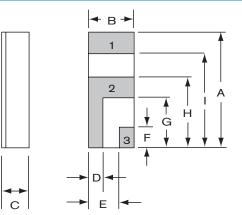
- Extensional mode
- Ideal for use with microprocessors
- Designed for low power applications
- Compatible with hybrid or PC board
- Low aging
- Full military testing available
- Ideal for battery operated applications
- Designed and manufactured in the USA

EQUIVALENT CIRCUIT



SUGGESTED LAND PATTERN





	TYP.		MAX.	
DIM	inches	mm	inches	mm
А	0.260	6.60	0.275	6.99
В	0.094	2.39	0.108	2.74
С	-	-	see below	
D	0.035	0.89	0.045	1.14
Е	0.059	1.50	0.069	1.75
F	0.050	1.27	0.060	1.52
G	0.105	2.67	0.115	2.92
Н	0.155	3.94	0.165	4.19
I	0.210	5.33	0.220	5.59
DIM "C"	GLASS LID		CERAMIC LID	
MAX	inches	mm	inches	mm
SM1	0.065	1.65	0.075	1.91
SM2/SM4	0.067	1.70	0.077	1.96
SM3/SM5	0.070	1.78	0.080	2.03

Note: Terminal 1 is electrically connected internally to terminal 3



SPECIFICATIONS

Specifications are typical at 25°C unless otherwise noted. Specifications are subject to change without notice.

	0		
Frequency Range	<u>760 kHz - 1.35 MHz</u>		
Functional Mode	Extensional		
Calibration Tolerance ¹	± 500 ppm (0.05%)		
	± 1000 ppm (0.1%)		
	± 10000 ppm (1.0%)		
Load Capacitance	7 pF		
Motional Resistance (R1)	5 kΩ MAX		
Motional Capacitance (C1)	1.2fF		
Quality Factor (Q)	150 k		
Shunt Capacitance (C ₀)	1.0 pF		
Drive Level	3 μW MAX		
Turning Point (T ₀) ²	35°C		
Temperature Coefficient (k)	-0.035 ppm/°C ²		
Aging, first year	5 ppm MAX		
Shock, survival	1000 g, 0.3 ms, $1/_2$ sine		
Vibration, survival	10 g RMS, 20-1,000 Hz random		
Operating Temp. Range	-10° C to $+70^{\circ}$ C (Commercial)		
	-40° C to $+85^{\circ}$ C (Industrial)		
	-55°C to +125°C (Military)		
Storage Temp. Range	-55°C to +125°C		

Note: Frequency f at temperature T is related to frequency f_0 at turning point temperature T_0 by: $\frac{f_0 - f_0}{f_0} = k(T - T_0)^2$

1. Tighter frequency calibration available.

2. Other turning points available.

TERMINATIONS

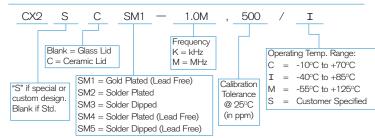
Termination
Gold Plated
Solder Plated
Solder Dipped
Solder Plated (Lead Free)
Solder Dipped (Lead Free)

PACKAGING OPTIONS

CX2SM - Tray Pack

-16mm tape, 7" or 13" reels (Reference tape and reel data sheet 10109)

HOW TO ORDER CX2SM CRYSTALS



TYPICAL APPLICATION FOR A PIERCE OSCILLATOR

The low profile CX miniature surface mount crystal is ideal for small, high density, battery operated portable products. The CX crystal designed in a Pierce oscillator (single inverter) circuit provides very low current consumption and high stability. A conventional CMOS Pierce oscillator circuit is shown below. The crystal is effectively inductive and in a PI-network circuit with C_D and C_G provides the additional phase shift necessary to sustain oscillation. The oscillation frequency (f_0) is 15 to 150 ppm above the crystal's series resonant frequency (f_S).

Drive Level

 R_A is used to limit the crystal's drive level by forming a voltage divider between R_A and $C_D.\ R_A$ also stabilizes the oscillator against changes in the amplifiers output resistance (R_0). R_A should be increased for higher voltage operation.

Load Capacitance

The CX crystal calibration tolerance is influenced by the effective circuit capacitances, specified as the load capacitance (C_L). C_L is approximately equal to:

$$C_{L} = \frac{C_{D} \times C_{G}}{C_{D} + C_{G}} + C_{S}$$
(1)

NOTE: C_D and C_G include stray layout to ground and C_S is the stray shunt capacitance between the crystal terminal. In practice, the effective value of C_L will be less than that calculated from C_D , C_G and C_S values because of the effect of the amplifier output resistance. C_S should be minimized.

The oscillation frequency (f_0) is approximately equal to:

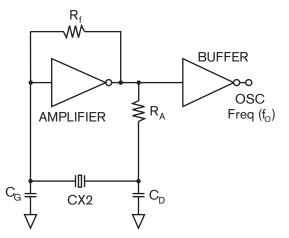
$$f_0 = f_S \left[1 + \frac{C_1}{2(C_0 + C_L)} \right] \quad (2)$$

Where f_{S} = Series resonant frequency of the crystal

 C_1 = Motional Capacitance

 C_0 = Shunt Capacitance

CONVENTIONAL CMOS PIERCE OSCILLATOR CIRCUIT



10135 - Rev C

